

HD74LV157A

Quad. 2-to-1 line Data Selectors / Multiplexers (Noninverted Outputs)

REJ03D0318-0200Z (Previous ADE-205-263 (Z)) Rev.2.00 Jun. 03, 2004

Description

The HD74LV157A has four 2-input digital multiplexers with common select and strobe inputs. When the strobe input is low, a 4-bit word is selected from one of two sources and is routed to the four outputs.

The device provides true data.

Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- All outputs V_0 (Max.) = 5.5 V (@ V_{CC} = 0 V)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.3 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Output current ± 6 mA (@V_{CC} = 3.0 V to 3.6 V), ± 12 mA (@V_{CC} = 4.5 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV157AFPEL	SOP-16 pin(JEITA)	FP-16DAV	FP	EL (2,000 pcs/reel)
HD74LV157ARPEL	SOP-16 pin(JEDEC)	FP-16DNV	RP	EL (2,500 pcs/reel)
HD74LV157ATELL	TSSOP-16 pin	TTP-16DAV	Т	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

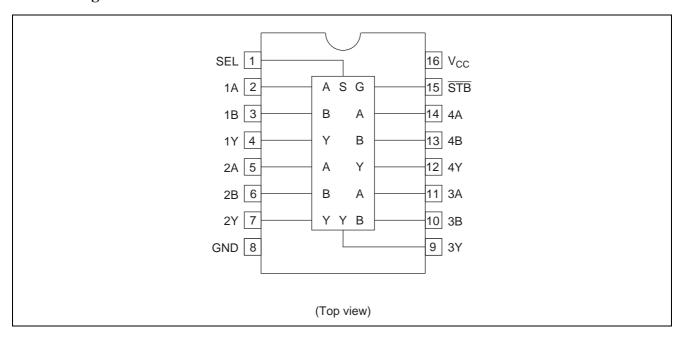
Function Table

Inputs

STB	SEL	Α	В	Output
Н	Χ	Х	Χ	L
L	L	L	Χ	L
L	L	Н	Χ	Н
L	Н	Х	L	L
L	Н	Χ	Н	H

Note: H: High level L: Low level X: Immaterial

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	Vcc	-0.5 to 7.0	V	
Input voltage range*1	Vı	-0.5 to 7.0	V	
Output voltage range*1, 2	Vo	-0.5 to $V_{CC} + 0.5$	V	Output: H or L
		-0.5 to 7.0	-	V _{CC} : OFF
Input clamp current	I _{IK}	-20	mA	V _I < 0
Output clamp current	I _{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	Io	±25	mA	$V_O = 0$ to V_{CC}
Continuous current through V _{CC} or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation	P _T	785	mW	SOP
at Ta = 25°C (in still air)* ³		500	-	TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

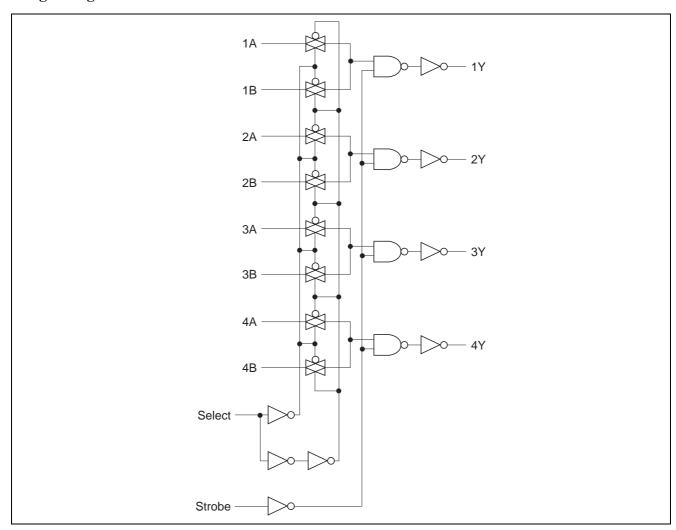
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	Vcc	2.0	5.5	V	
Input voltage range	VI	0	5.5	V	
Output voltage range	Vo	0	V _{CC}	V	H or L
Output current	I _{OH}	_	-50	μΑ	V _{CC} = 2.0 V
		_	-2	mA	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	-6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	-12		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
	I _{OL}	_	50	μΑ	V _{CC} = 2.0 V
		_	2	mA	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Input transition rise or fall rate	$\Delta t/\Delta v$	0	200	ns/V	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		0	100		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



DC Electrical Characteristics

 $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V _{CC} (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	V_{IH}	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{CC} \times 0.7$	_	_		
		3.0 to 3.6	$V_{CC} \times 0.7$	_	_		
		4.5 to 5.5	$V_{\text{CC}} \times 0.7$	_	_		
	V _{IL}	2.0	_	_	0.5		
		2.3 to 2.7	_	_	$V_{\text{CC}}\!\times\!0.3$		
		3.0 to 3.6	_	_	$V_{CC}\!\times\!0.3$		
		4.5 to 5.5	_	_	$V_{CC}\!\times\!0.3$		
Output voltage	V_{OH}	Min to Max	$V_{CC} - 0.1$	_	_	V	$I_{OH} = -50 \mu A$
		2.3	2.0	_	_		$I_{OH} = -2 \text{ mA}$
		3.0	2.48	_	_		$I_{OH} = -6 \text{ mA}$
		4.5	3.8	_	_		$I_{OH} = -12 \text{ mA}$
	V_{OL}	Min to Max	_	_	0.1		$I_{OL} = 50 \mu A$
		2.3	_	_	0.4		$I_{OL} = 2 \text{ mA}$
		3.0	_	_	0.44		$I_{OL} = 6 \text{ mA}$
		4.5	_	_	0.55		I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_I = 5.5 \text{ V or GND}$
Quiescent supply	I _{CC}	5.5	_	_	20	μΑ	$V_I = V_{CC}$ or GND, $I_O = 0$
current							
Output leakage current	I _{OFF}	0	_	_	5	μΑ	V_1 or $V_0 = 0$ V to 5.5 V
Input capacitance	C _{IN}	3.3		1.9		pF	$V_I = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

 $V_{CC}=2.5\pm0.2~V$

		Ta =	25°C		Ta = -40 to 85°C			Test	FROM	то
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t _{PLH} /t _{PHL}	_	9.8	15.9	1.0	19.5	ns	C _L = 15 pF	A or B	Υ
delay time		_	13.3	18.8	1.0	22.0		C _L = 50 pF		
		_	15.5	19.4	1.0	23.5		C _L = 15 pF	SEL	_
		_	15.7	22.3	1.0	26.0		C _L = 50 pF	_	
		_	15.8	19.8	1.0	24.0		C _L = 15 pF	STB	_
		_	14.8	22.7	1.0	26.5		C _L = 50 pF	_	

 $V_{CC} = 3.3 \pm 0.3 \ V$

		Ta =	25°C		Ta = -40 to 85°C			Test	FROM	то
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t _{PLH} /t _{PHL}	_	6.2	9.7	1.0	11.5	ns	C _L = 15 pF	A or B	Υ
delay time		_	8.7	13.2	1.0	15.0	<u> </u>	C _L = 50 pF		
		_	8.4	13.2	1.0	15.5	_	C _L = 15 pF	SEL	_
		_	10.9	16.7	1.0	19.0	_	C _L = 50 pF		
		_	8.7	13.6	1.0	16.0		C _L = 15 pF	STB	_
		_	11.2	17.1	1.0	19.5	_	C _L = 50 pF		

 $V_{CC} = 5.0 \pm 0.5~V$

		Ta =	25°C		Ta = -40 to 85°C			Test	FROM	то
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t _{PLH} /t _{PHL}	_	4.1	6.4	1.0	7.5	ns	C _L = 15 pF	A or B	Υ
delay time		_	5.6	8.4	1.0	9.5	<u> </u>	C _L = 50 pF		
		_	5.3	8.1	1.0	9.5	_	C _L = 15 pF	SEL	_
		_	6.8	10.1	1.0	11.5	_	C _L = 50 pF	_	
		_	5.6	8.6	1.0	10.0	_	C _L = 15 pF	STB	_
		_	7.1	10.6	1.0	12.0	_	C _L = 50 pF		

Operating Characteristics

 $C_L = 50 pF$

Ta = 2	5°C
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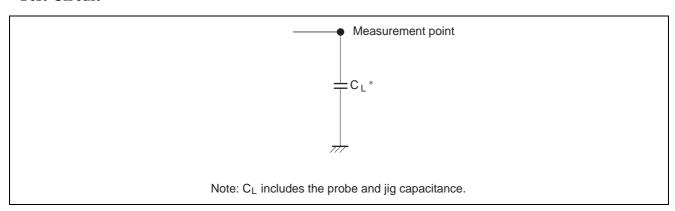
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	C_{PD}	3.3	_	10.0	_	pF	f = 10 MHz
		5.0	_	12.0	_		

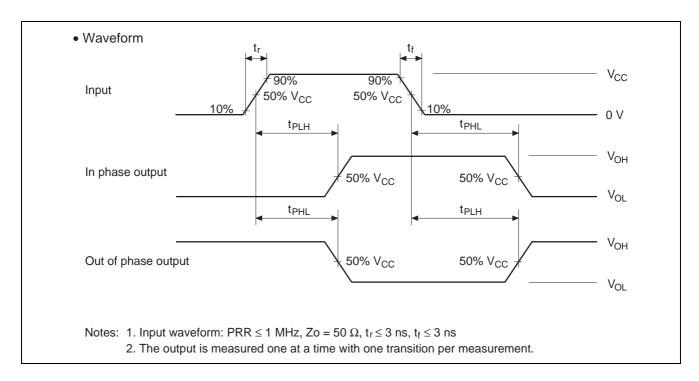
Noise Characteristics

 $C_L = 50 \text{ pF}$

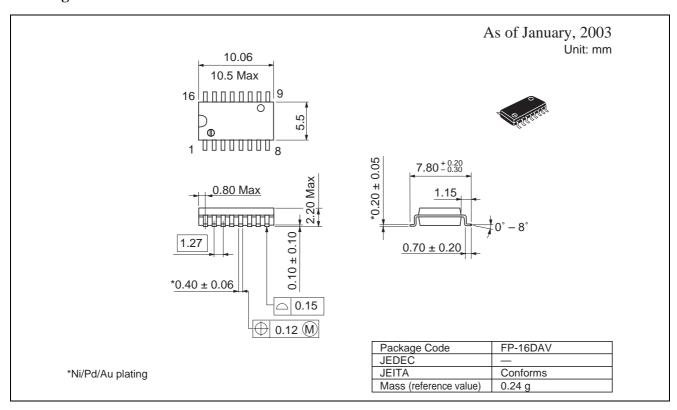
			Ta = 25°C				
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	Test Conditions
Quiet output, maximum dynamic V _{OL}	V _{OL (P)}	3.3	_	0.3	0.8	V	
Quiet output, minimum dynamic V _{OL}	$V_{OL\ (V)}$	3.3	_	-0.2	-0.8	V	
Quiet output, minimum dynamic V _{OH}	$V_{OH\ (V)}$	3.3	_	3.0	_	V	
High-level dynamic input voltage	$V_{\text{IH (D)}}$	3.3	2.31	_	_	V	
Low-level dynamic input voltage	$V_{\text{IL }(D)}$	3.3	_	_	0.99	V	

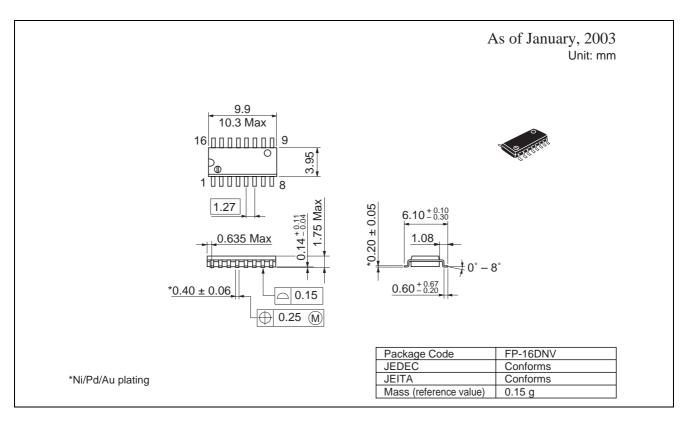
Test Circuit

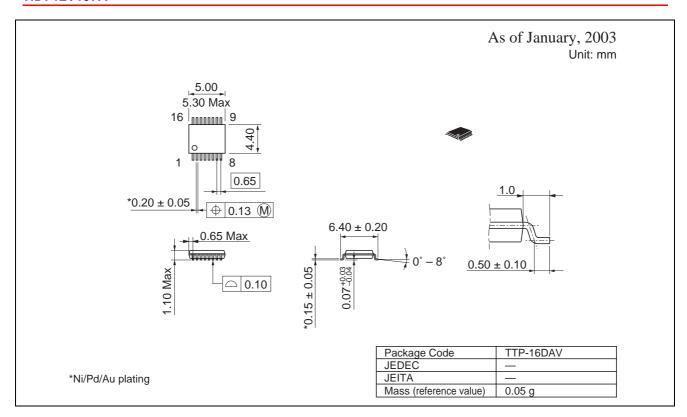




Package Dimensions







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